

Midium Power Transistors (-80V / -1.5A)

2SAR554P

● Structure

PNP Silicon epitaxial planar transistor

● Features

- 1) Low saturation voltage, typically
 $V_{CE(sat)} = -0.4V$ (Max.) ($I_C / I_B = -500mA / -25mA$)
- 2) High speed switching

● Applications

Driver

● Packaging specifications

Type	Package	Taping
	Code	T100
	Basic ordering unit (pieces)	1000
2SAR554P		○

● Absolute maximum ratings (Ta = 25°C)

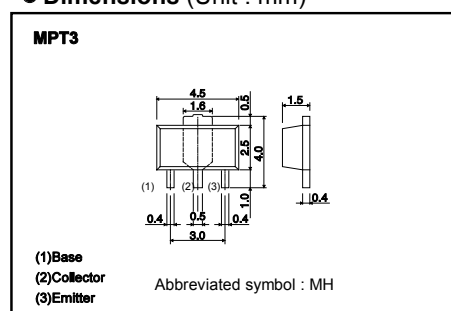
Parameter	Symbol	Limits	Unit
Collector-base voltage	V_{CBO}	-80	V
Collector-emitter voltage	V_{CEO}	-80	V
Emitter-base voltage	V_{EBO}	-6	V
Collector current	DC	I_C	-1.5
	Pulsed	I_{CP}^{*1}	-3
Power dissipation	P_D^{*2}	0.5	W
	P_D^{*3}	2	W
Junction temperature	T_j	150	°C
Range of storage temperature	T_{stg}	-55 to 150	°C

*1 $P_w=10ms$, Single Pulse

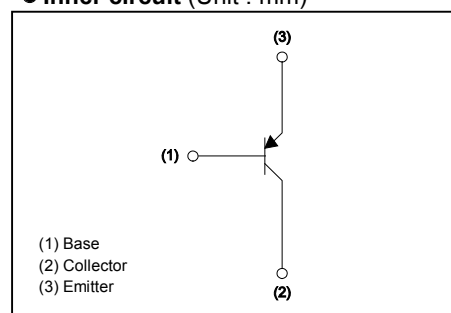
*2 Each terminal mounted on a recommended land.

*3 Mounted on a ceramic board. (40x40x0.7mm³)

● Dimensions (Unit : mm)



● Inner circuit (Unit : mm)

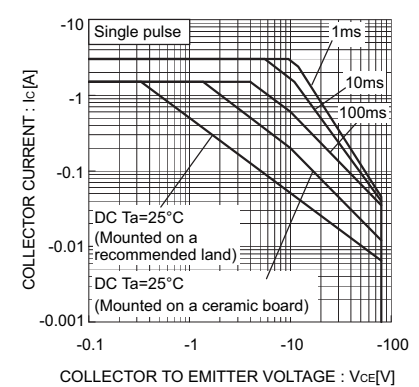
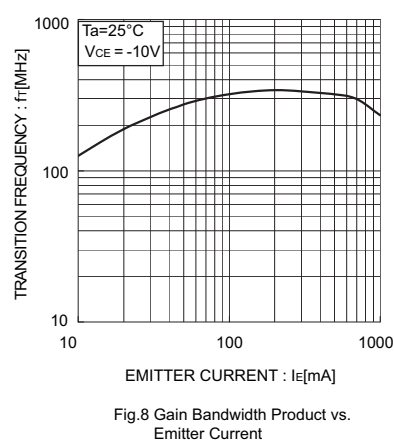
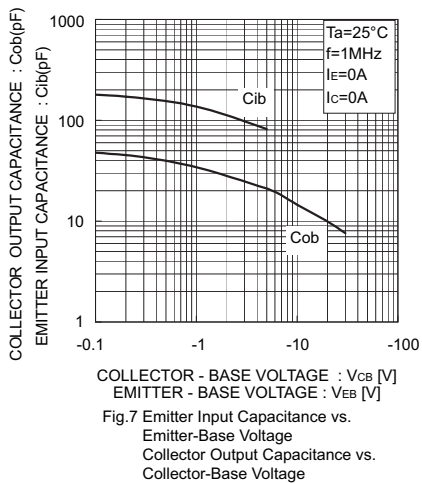
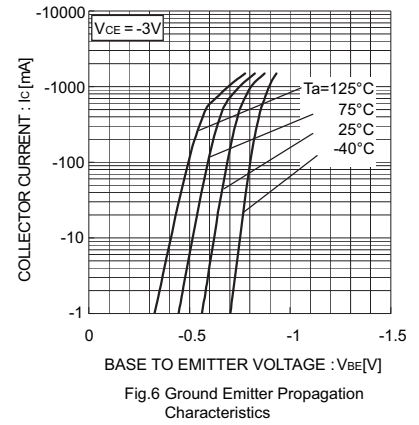
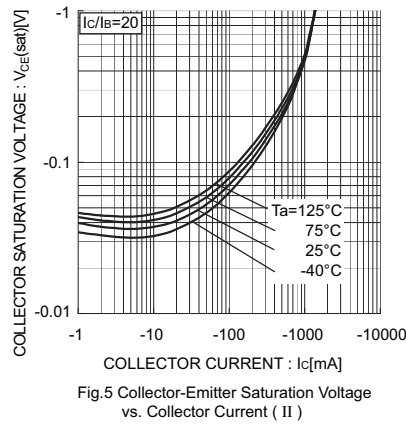
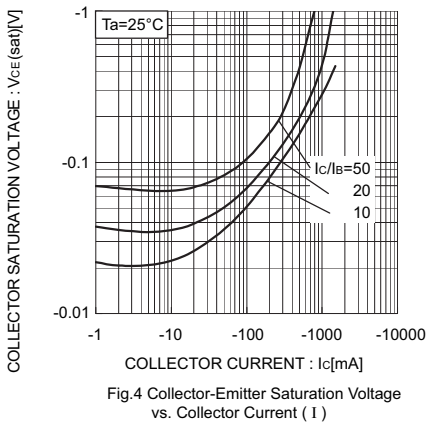
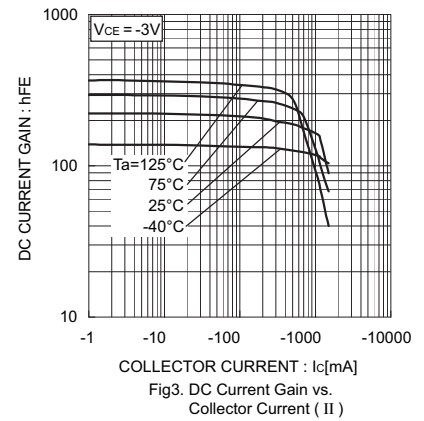
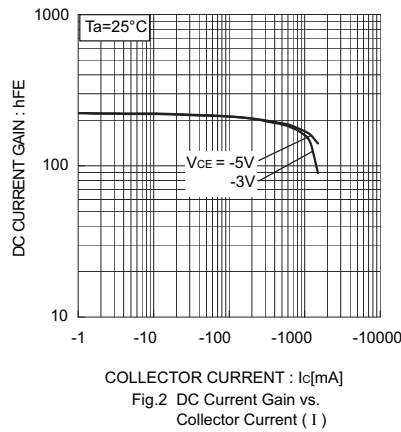
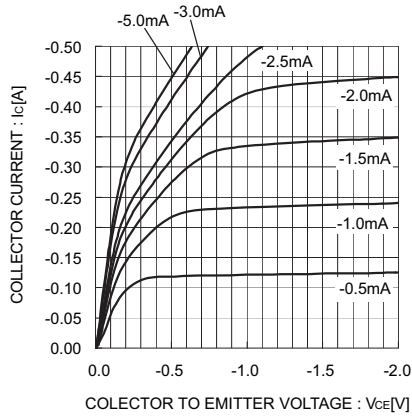


●Electrical characteristic (Ta = 25°C)

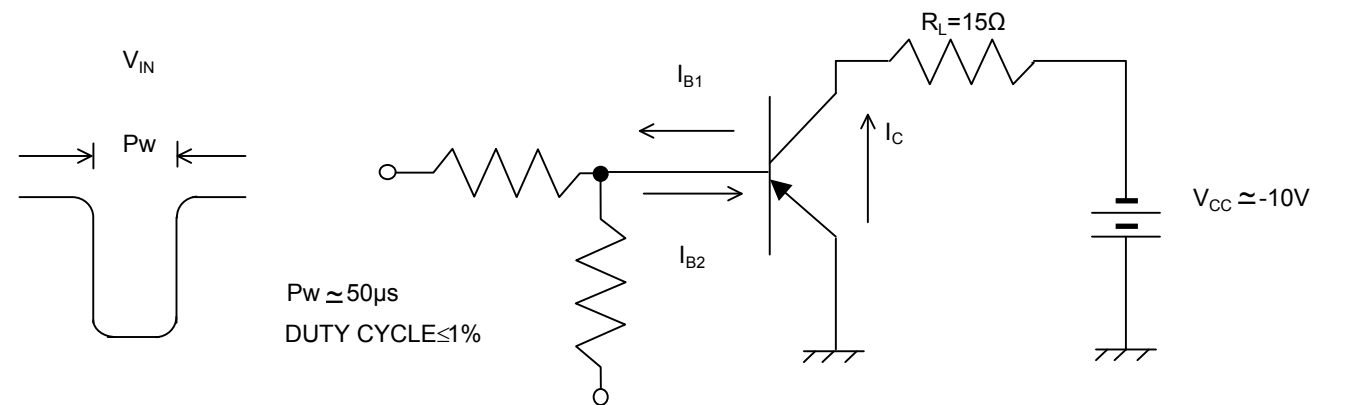
Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	BV_{CEO}	-80	-	-	V	$I_C = -1\text{mA}$
Collector-base breakdown voltage	BV_{CBO}	-80	-	-	V	$I_C = -100\mu\text{A}$
Emitter-base breakdown voltage	BV_{EBO}	-6	-	-	V	$I_E = -100\mu\text{A}$
Collector cut-off current	I_{CBO}	-	-	-1	μA	$V_{CB} = -80\text{V}$
Emitter cut-off current	I_{EBO}	-	-	-1	μA	$V_{EB} = -4\text{V}$
Collector-emitter saturation voltage	$V_{CE(sat)}$	-	-200	-400	mV	$I_C = -500\text{mA}$, $I_B = -25\text{mA}$
DC current gain	h_{FE}	120	-	390	-	$V_{CE} = -3\text{V}$, $I_C = -100\text{mA}$
Transition frequency	f_T	-	340	-	MHz	$V_{CE} = -10\text{V}$ $I_E = 200\text{mA}$, $f = 100\text{MHz}$
Collector output capacitance	C_{ob}	-	15	-	pF	$V_{CB} = -10\text{V}$, $I_E = 0\text{A}$ $f = 1\text{MHz}$
Turn-on time	t_{on}^{*1}	-	50	-	ns	$I_C = -0.7\text{A}$, $I_{B1} = -70\text{mA}$, $I_{B2} = 70\text{mA}$, $V_{CC} \approx -10\text{V}$
Storage time	t_{stg}^{*1}	-	300	-	ns	
Fall time	t_f^{*1}	-	50	-	ns	

*1 See switching time test circuit

●Electrical characteristic curves

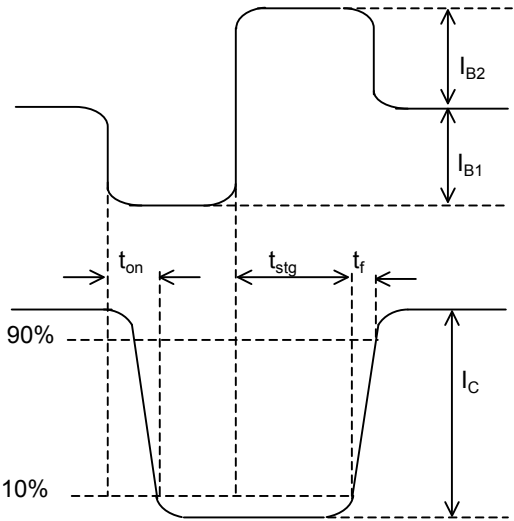


●Switching time test circuit



BASE CURENT WAVEFORM

COLLECTOR CURRENT WAVEFORM



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